



# PHKD13N03LT

Dual N-channel TrenchMOS logic level FET

Rev. 5 — 27 December 2011

Product data sheet

## 1. Product profile

### 1.1 General description

Dual logic level N-channel enhancement mode Field-Effect Transistor (FET) in a plastic package using TrenchMOS technology. This product is designed and qualified for use in computing, communications, consumer and industrial applications only.

### 1.2 Features and benefits

- Low conduction losses due to low on-state resistance
- Simple gate drive required due to low gate charge
- Suitable for high frequency applications due to fast switching characteristics

### 1.3 Applications

- DC-to-DC convertors
- Lithium-ion battery applications
- Notebook computers
- Portable equipment

### 1.4 Quick reference data

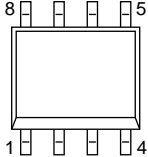
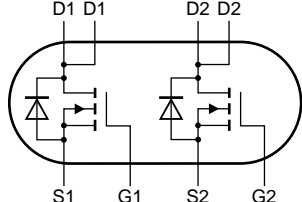
Table 1. Quick reference data

| Symbol                         | Parameter                        | Conditions  | Min | Typ | Max  | Unit       |
|--------------------------------|----------------------------------|---|-----|-----|------|------------|
| $V_{DS}$                       | drain-source voltage             | $T_j \geq 25\text{ °C}; T_j \leq 150\text{ °C}$   | -   | -   | 30   | V          |
| $I_D$                          | drain current                    | $T_{sp} = 25\text{ °C}; V_{GS} = 10\text{ V};$ see <a href="#">Figure 1</a> ; <a href="#">[1]</a><br>see <a href="#">Figure 3</a> | -   | -   | 10.4 | A          |
| $P_{tot}$                      | total power dissipation          | $T_{sp} = 25\text{ °C};$ see <a href="#">Figure 2</a>   | -   | -   | 3.57 | W          |
| <b>Static characteristics</b>  |                                  |   |     |     |      |            |
| $R_{DSon}$                     | drain-source on-state resistance | $V_{GS} = 10\text{ V}; I_D = 8\text{ A}; T_j = 25\text{ °C};$<br>see <a href="#">Figure 9</a> ; see <a href="#">Figure 10</a>     | -   | 17  | 20   | m $\Omega$ |
| <b>Dynamic characteristics</b> |                                  |   |     |     |      |            |
| $Q_{GD}$                       | gate-drain charge                | $V_{GS} = 5\text{ V}; I_D = 5\text{ A}; V_{DS} = 15\text{ V};$<br>$T_j = 25\text{ °C};$ see <a href="#">Figure 11</a>             | -   | 3.9 | -    | nC         |

[1] Single device conducting.

## 2. Pinning information

Table 2. Pinning information

| Pin | Symbol | Description | Simplified outline   | Graphic symbol  |
|-----|--------|-------------|--|---|
| 1   | S1     | source1     |  <p>SOT96-1 (SO8)</p> |  <p>mbk725</p> |
| 2   | G1     | gate1       |  |   |
| 3   | S2     | source2     |  |   |
| 4   | G2     | gate2       |  |   |
| 5   | D2     | drain2      |  |   |
| 6   | D2     | drain2      |  |   |
| 7   | D1     | drain1      |  |   |
| 8   | D1     | drain       |  |   |

## 3. Ordering information

Table 3. Ordering information

| Type number | Package |   |         |
|-------------|---------|---|---------|
|             | Name    | Description   | Version |
| PHKD13N03LT | SO8     | plastic small outline package; 8 leads; body width 3.9 mm | SOT96-1 |

## 4. Limiting values

Table 4. Limiting values

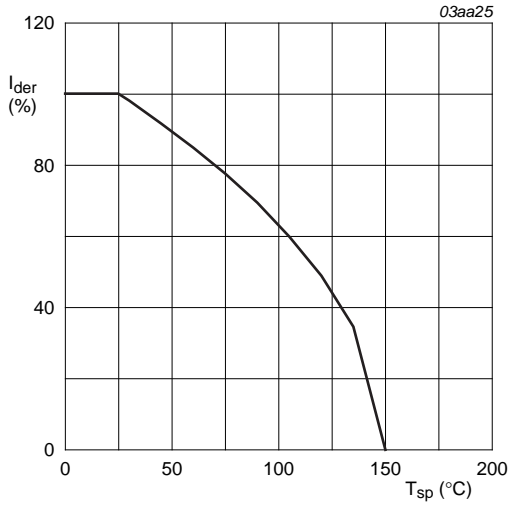
In accordance with the Absolute Maximum Rating System (IEC 60134).

| Symbol    | Parameter               | Conditions   | Min | Max  | Unit |   |
|-----------|-------------------------|--|-----|------|------|---|
| $V_{DS}$  | drain-source voltage    | $T_j \geq 25\text{ °C}$ ; $T_j \leq 150\text{ °C}$   | -   | 30   | V    |   |
| $V_{DGR}$ | drain-gate voltage      | $T_j \geq 25\text{ °C}$ ; $T_j \leq 150\text{ °C}$ ; $R_{GS} = 20\text{ k}\Omega$                              | -   | 30   | V    |   |
| $V_{GS}$  | gate-source voltage     |  | -20 | 20   | V    |   |
| $I_D$     | drain current           | $T_{sp} = 100\text{ °C}$ ; $V_{GS} = 10\text{ V}$ ; see <a href="#">Figure 1</a>                               | [1] | -    | 6.6  | A |
|           |                         | $T_{sp} = 25\text{ °C}$ ; $V_{GS} = 10\text{ V}$ ; see <a href="#">Figure 1</a> ; see <a href="#">Figure 3</a> | [1] | -    | 10.4 | A |
| $I_{DM}$  | peak drain current      | $T_{sp} = 25\text{ °C}$ ; pulsed; $t_p \leq 10\text{ }\mu\text{s}$ ; see <a href="#">Figure 3</a>              | [1] | -    | 42   | A |
| $P_{tot}$ | total power dissipation | $T_{sp} = 25\text{ °C}$ ; see <a href="#">Figure 2</a>   | -   | 3.57 | W    |   |
| $T_{stg}$ | storage temperature     |  | -55 | 150  | °C   |   |
| $T_j$     | junction temperature    |  | -55 | 150  | °C   |   |

### Source-drain diode

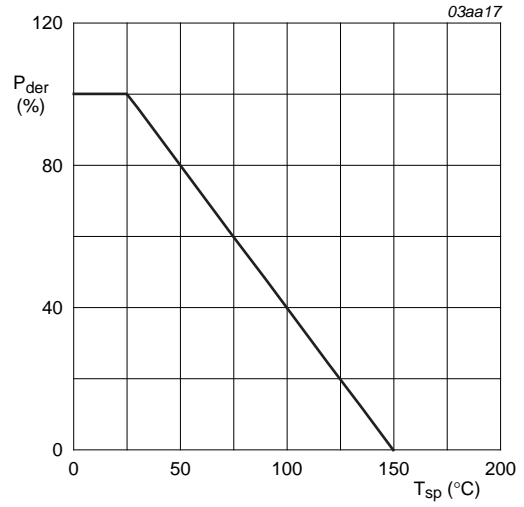
|          |                     |  |     |   |     |   |
|----------|---------------------|--|-----|---|-----|---|
| $I_S$    | source current      | $T_{sp} = 25\text{ °C}$  | [1] | - | 3.2 | A |
| $I_{SM}$ | peak source current | $T_{sp} = 25\text{ °C}$ ; pulsed; $t_p \leq 10\text{ }\mu\text{s}$ | [1] | - | 42  | A |

[1] Single device conducting.



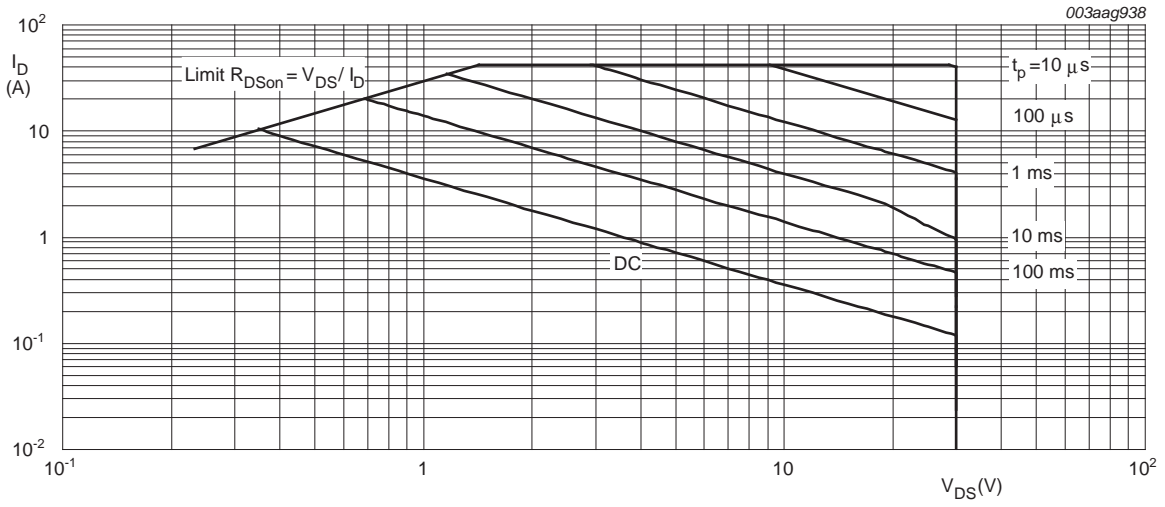
$$I_{der} = \frac{I_D}{I_{D(25^\circ\text{C})}} \times 100\%$$

Fig 1. Normalized continuous drain current as a function of solder point temperature



$$P_{der} = \frac{P_{tot}}{P_{tot(25^\circ\text{C})}} \times 100\%$$

Fig 2. Normalized total power dissipation as a function of solder point temperature



$T_{mb} = 25^\circ\text{C}$ ;  $I_{DM}$  is a single pulse

Fig 3. Safe operating area; continuous and peak drain currents as a function of drain-source voltage

### 5. Thermal characteristics

Table 5. Thermal characteristics

| Symbol         | Parameter  | Conditions   | Min | Typ | Max | Unit |
|----------------|--|--|-----|-----|-----|------|
| $R_{th(j-sp)}$ | thermal resistance from junction to solder point | see <a href="#">Figure 4</a>                           | -   | -   | 35  | K/W  |
| $R_{th(j-a)}$  | thermal resistance from junction to ambient      | minimum footprint ; mounted on a printed-circuit board | -   | 70  | -   | K/W  |

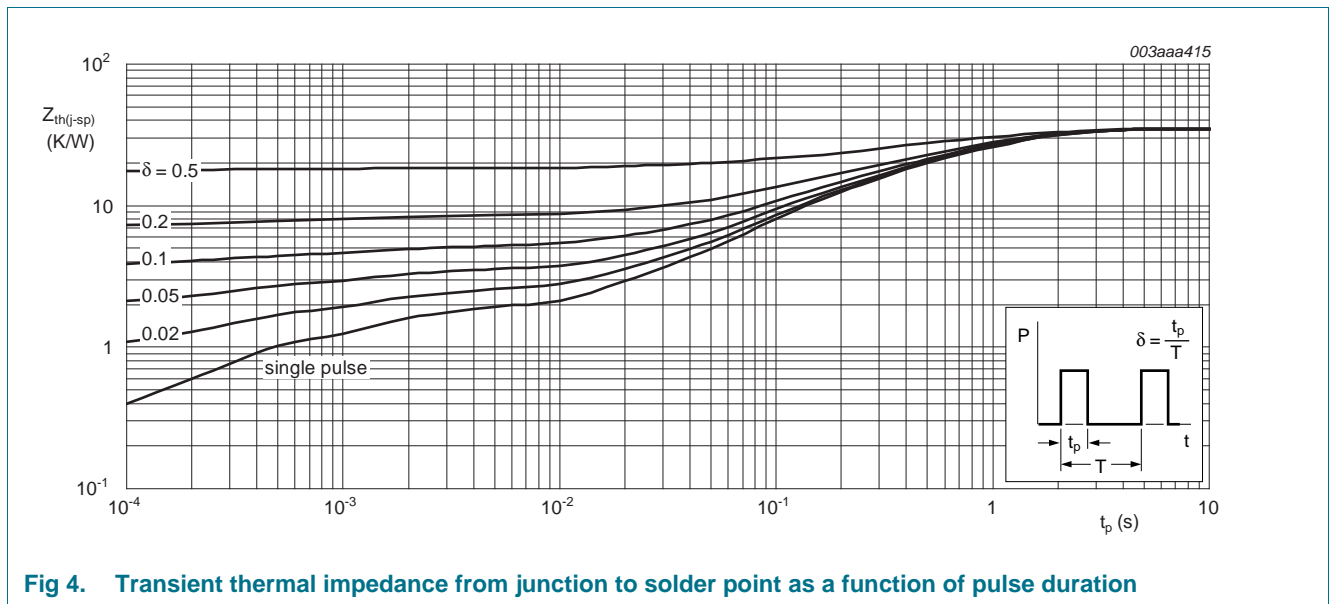


Fig 4. Transient thermal impedance from junction to solder point as a function of pulse duration

## 6. Characteristics

Table 6. Characteristics

| Symbol                         | Parameter                        | Conditions  | Min | Typ  | Max | Unit          |
|--------------------------------|----------------------------------|---|-----|------|-----|---------------|
| <b>Static characteristics</b>  |                                  |   |     |      |     |               |
| $V_{(BR)DSS}$                  | drain-source breakdown voltage   | $I_D = 250 \mu\text{A}; V_{GS} = 0 \text{ V}; T_j = -55 \text{ }^\circ\text{C}$   | 27  | -    | -   | V             |
|                                |                                  | $I_D = 250 \mu\text{A}; V_{GS} = 0 \text{ V}; T_j = 25 \text{ }^\circ\text{C}$  | 30  | -    | -   | V             |
| $V_{GS(th)}$                   | gate-source threshold voltage    | $I_D = 250 \mu\text{A}; V_{DS} = V_{GS}; T_j = -55 \text{ }^\circ\text{C};$<br>see <a href="#">Figure 8</a>   | -   | -    | 2.2 | V             |
|                                |                                  | $I_D = 250 \mu\text{A}; V_{DS} = V_{GS}; T_j = 150 \text{ }^\circ\text{C};$<br>see <a href="#">Figure 8</a>   | 0.5 | -    | -   | V             |
|                                |                                  | $I_D = 250 \mu\text{A}; V_{DS} = V_{GS}; T_j = 25 \text{ }^\circ\text{C};$<br>see <a href="#">Figure 8</a>  | 1   | 1.5  | 2   | V             |
| $I_{DSS}$                      | drain leakage current            | $V_{DS} = 24 \text{ V}; V_{GS} = 0 \text{ V}; T_j = 25 \text{ }^\circ\text{C}$  | -   | -    | 1   | $\mu\text{A}$ |
|                                |                                  | $V_{DS} = 24 \text{ V}; V_{GS} = 0 \text{ V}; T_j = 100 \text{ }^\circ\text{C}$   | -   | -    | 5   | $\mu\text{A}$ |
| $I_{GSS}$                      | gate leakage current             | $V_{GS} = 20 \text{ V}; V_{DS} = 0 \text{ V}; T_j = 25 \text{ }^\circ\text{C}$  | -   | -    | 100 | nA            |
|                                |                                  | $V_{GS} = -20 \text{ V}; V_{DS} = 0 \text{ V}; T_j = 25 \text{ }^\circ\text{C}$   | -   | -    | 100 | nA            |
| $R_{DS(on)}$                   | drain-source on-state resistance | $V_{GS} = 10 \text{ V}; I_D = 8 \text{ A}; T_j = 150 \text{ }^\circ\text{C};$<br>see <a href="#">Figure 9</a> ; see <a href="#">Figure 10</a>                                 | -   | -    | 34  | m $\Omega$    |
|                                |                                  | $V_{GS} = 4.5 \text{ V}; I_D = 7 \text{ A}; T_j = 25 \text{ }^\circ\text{C};$<br>see <a href="#">Figure 9</a>   | -   | 21   | 26  | m $\Omega$    |
|                                |                                  | $V_{GS} = 10 \text{ V}; I_D = 8 \text{ A}; T_j = 25 \text{ }^\circ\text{C};$<br>see <a href="#">Figure 9</a> ; see <a href="#">Figure 10</a>                                  | -   | 17   | 20  | m $\Omega$    |
| <b>Dynamic characteristics</b> |                                  |   |     |      |     |               |
| $Q_{G(tot)}$                   | total gate charge                | $I_D = 5 \text{ A}; V_{DS} = 15 \text{ V}; V_{GS} = 5 \text{ V};$<br>$T_j = 25 \text{ }^\circ\text{C};$ see <a href="#">Figure 11</a>   | -   | 10.7 | -   | nC            |
| $Q_{GS}$                       | gate-source charge               |   | -   | 2.7  | -   | nC            |
| $Q_{GD}$                       | gate-drain charge                |   | -   | 3.9  | -   | nC            |
| $C_{iss}$                      | input capacitance                | $V_{DS} = 15 \text{ V}; V_{GS} = 0 \text{ V}; f = 1 \text{ MHz};$<br>$T_j = 25 \text{ }^\circ\text{C};$ see <a href="#">Figure 12</a>   | -   | 752  | -   | pF            |
| $C_{oss}$                      | output capacitance               |   | -   | 200  | -   | pF            |
| $C_{rss}$                      | reverse transfer capacitance     |   | -   | 130  | -   | pF            |
| $t_{d(on)}$                    | turn-on delay time               | $V_{DS} = 15 \text{ V}; R_L = 10 \text{ }^\circ\Omega; V_{GS} = 10 \text{ V};$<br>$R_{G(ext)} = 6 \text{ }^\circ\Omega; T_j = 25 \text{ }^\circ\text{C}; I_D = 1.5 \text{ A}$ | -   | 6    | -   | ns            |
| $t_r$                          | rise time                        |   | -   | 7    | -   | ns            |
| $t_{d(off)}$                   | turn-off delay time              |   | -   | 23   | -   | ns            |
| $t_f$                          | fall time                        |   | -   | 11   | -   | ns            |
| <b>Source-drain diode</b>      |                                  |   |     |      |     |               |
| $V_{SD}$                       | source-drain voltage             | $I_S = 7 \text{ A}; V_{GS} = 0 \text{ V}; T_j = 25 \text{ }^\circ\text{C};$<br>see <a href="#">Figure 13</a>  | -   | 0.86 | 1.1 | V             |
| $t_{rr}$                       | reverse recovery time            | $I_S = 7 \text{ A}; dI_S/dt = -100 \text{ A}/\mu\text{s}; V_{GS} = 0 \text{ V};$<br>$V_{DS} = 30 \text{ V}; T_j = 25 \text{ }^\circ\text{C}$                                  | -   | 25   | -   | ns            |
| $Q_r$                          | recovered charge                 |   | -   | 5    | -   | nC            |

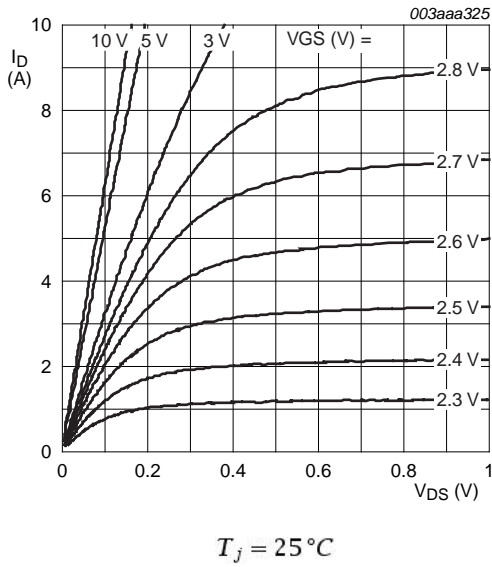


Fig 5. Output characteristics: drain current as a function of drain-source voltage; typical values

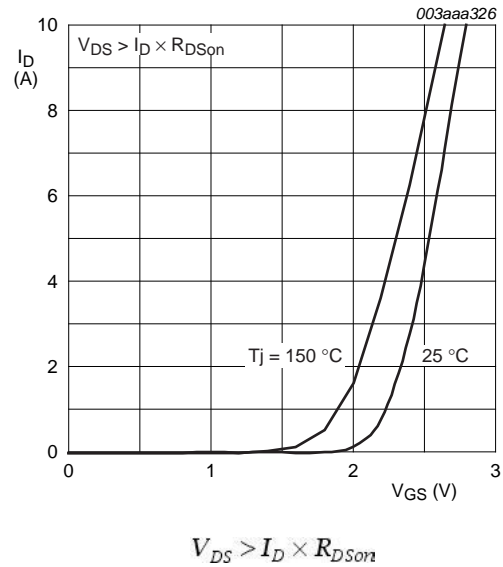


Fig 6. Transfer characteristics: drain current as a function of gate-source voltage; typical values

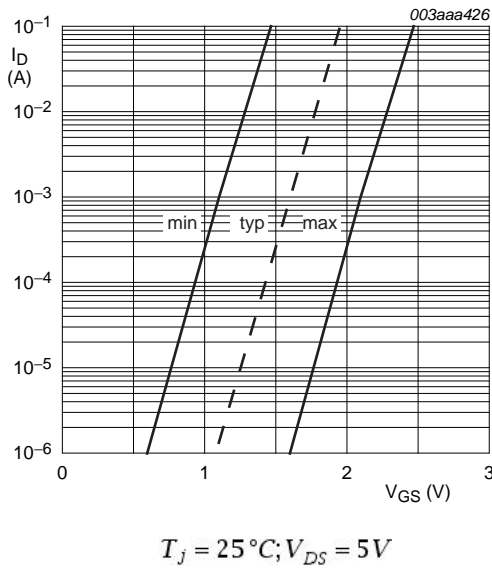


Fig 7. Sub-threshold drain current as a function of gate-source voltage

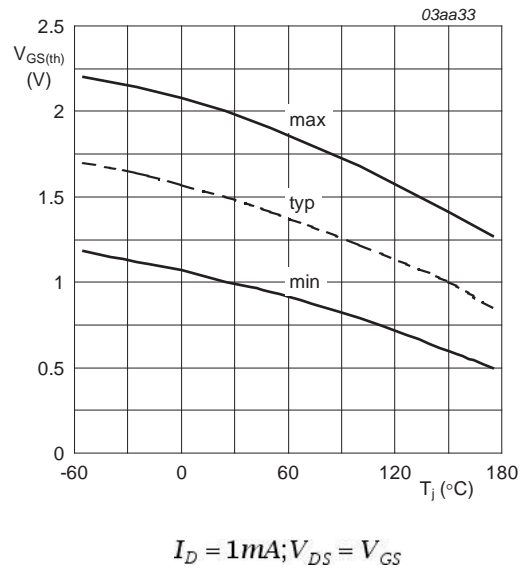
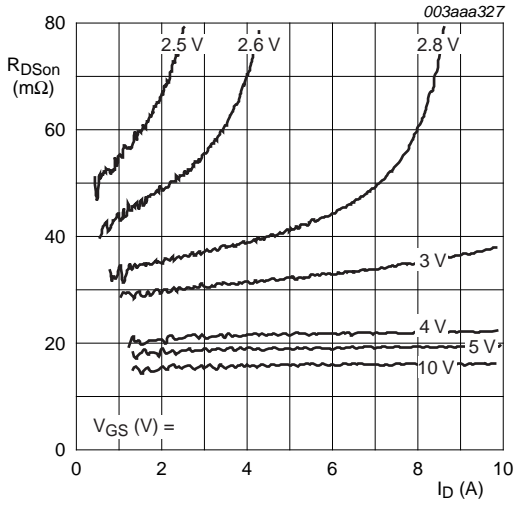
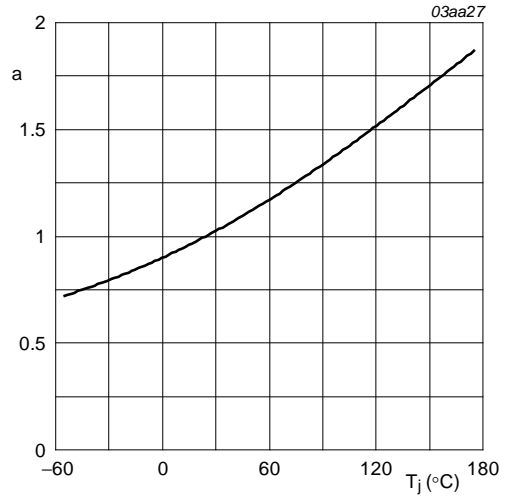


Fig 8. Gate-source threshold voltage as a function of junction temperature



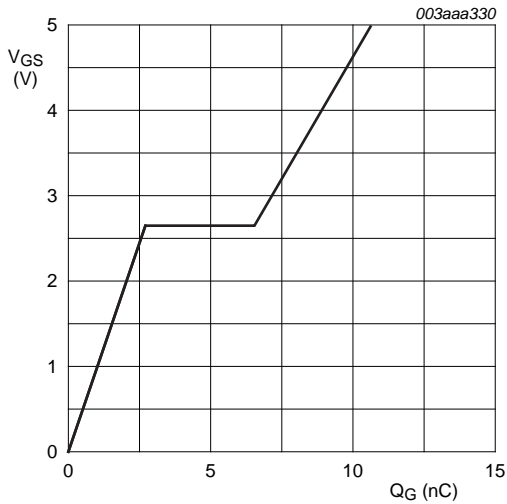
$T_j = 25^\circ\text{C}$

Fig 9. Drain-source on-state resistance as a function of drain current; typical values



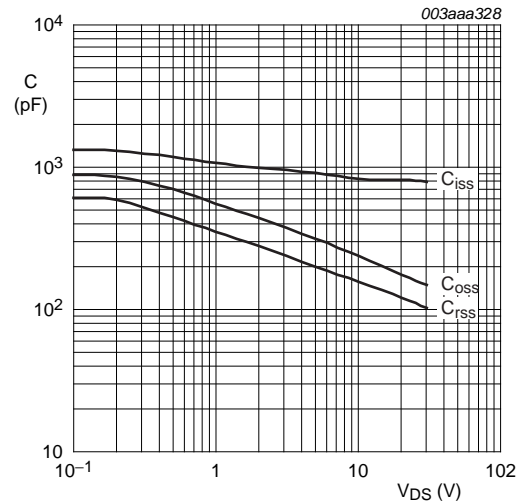
$$a = \frac{R_{DS(on)}}{R_{DS(on)@25^\circ\text{C}}}$$

Fig 10. Normalized drain-source on-state resistance factor as a function of junction temperature



$I_D = 8\text{ A}; V_{DD} = 15\text{ V}$

Fig 11. Gate-source voltage as a function of gate charge; typical values



$V_{GS} = 0\text{ V}; f = 1\text{ MHz}$

Fig 12. Input, output and reverse transfer capacitances as a function of drain-source voltage; typical values

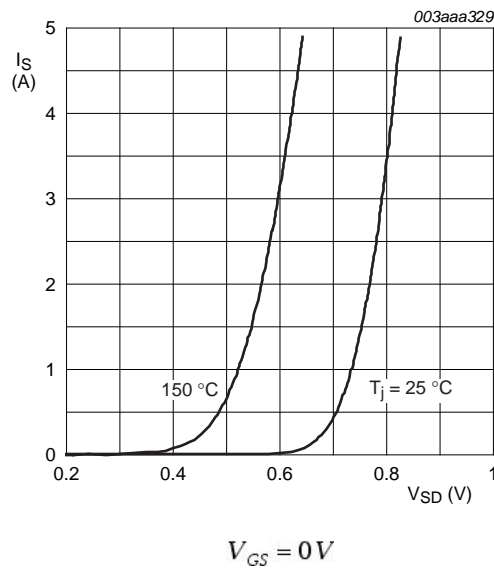


Fig 13. Source current as a function of source-drain voltage; typical values



7. Package outline

SO8: plastic small outline package; 8 leads; body width 3.9 mm

SOT96-1

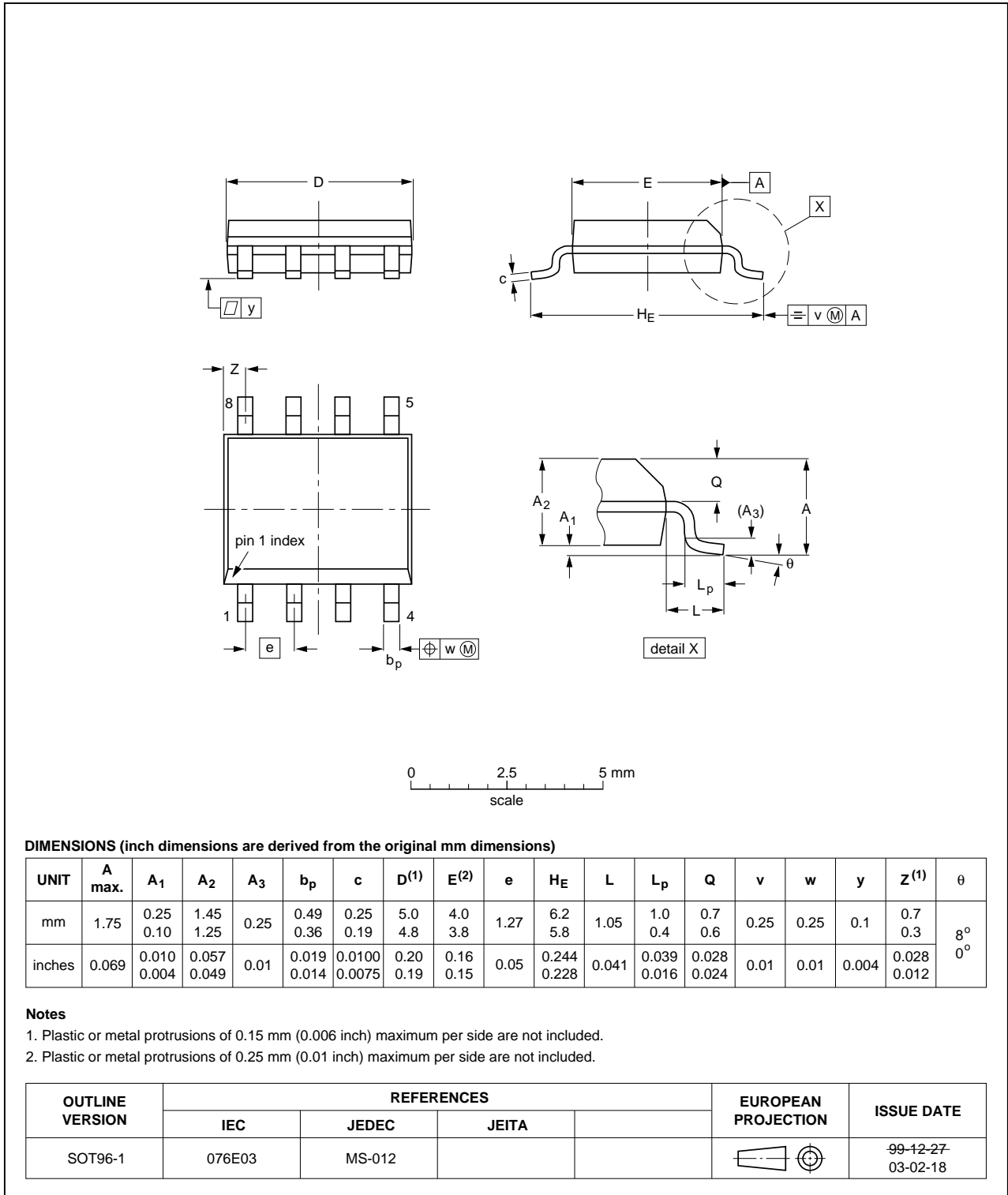


Fig 14. Package outline SOT96-1 (SO8)

## 8. Revision history

Table 7. Revision history

| Document ID     | Release date                  | Data sheet status  | Change notice | Supersedes      |
|-----------------|-------------------------------|--------------------|---------------|-----------------|
| PHKD13N03LT v.5 | 20111227                      | Product data sheet | -             | PHKD13N03LT v.4 |
| Modifications:  | • Various changes to content. |                    |               |                 |
| PHKD13N03LT v.4 | 20111122                      | Product data sheet | -             | PHKD13N03LT v.3 |

## 9. Legal information

### 9.1 Data sheet status

| Document status <sup>[1]</sup> <sup>[2]</sup> | Product status <sup>[3]</sup> | Definition  |
|---|-------------------------------|---|
| Objective [short] data sheet                  | Development                   | This document contains data from the objective specification for product development. |
| Preliminary [short] data sheet                | Qualification                 | This document contains data from the preliminary specification.                       |
| Product [short] data sheet                    | Production                    | This document contains the product specification.                                     |

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

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